

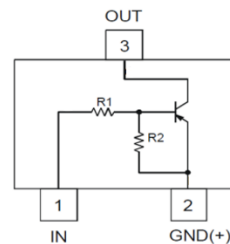
Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/contact-us) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

Part Number	R1(NOM)	R2(NOM)
DDTB113EC	1kΩ	1kΩ
DDTB123EC	2.2kΩ	2.2kΩ
DDTB143EC	4.7kΩ	4.7kΩ
DDTB114EC	10kΩ	10kΩ
DDTB122JC	0.22kΩ	4.7kΩ
DDTB113ZC	1kΩ	10kΩ
DDTB123YC	2.2kΩ	10kΩ
DDTB133HC	3.3kΩ	10kΩ
DDTB123TC	2.2kΩ	Open
DDTB143TC	4.7kΩ	Open
DDTB114TC	10kΩ	Open
DDTB114GC	0	10kΩ



Top View



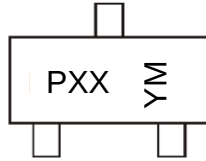
Device Schematic

Ordering Information (Note 4)

Part Number	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
						Qty.	Carrier
DDTB113EC-7-F	Obsolete	Standard	P60	7	8	3,000	Reel
DDTB123EC-7-F	Obsolete	Standard	P61	7	8	3,000	Reel
DDTB143EC-7-F	Obsolete	Standard	P62	7	8	3,000	Reel
DDTB114EC-7-F	Active	Standard	P63	7	8	3,000	Reel
DDTB122JC-7-F	Obsolete	Standard	P64	7	8	3,000	Reel
DDTB113ZC-7-F	Active	Standard	P65	7	8	3,000	Reel
DDTB123YC-7-F	Active	Standard	P66	7	8	3,000	Reel
DDTB133HC-7-F	Obsolete	Standard	P67	7	8	3,000	Reel
DDTB123TC-7-F	Obsolete	Standard	P69	7	8	3,000	Reel
DDTB143TC-7-F	Obsolete	Standard	P70	7	8	3,000	Reel
DDTB114TC-7-F	Obsolete	Standard	P71	7	8	3,000	Reel
DDTB114GC-7-F	Obsolete	Standard	P72	7	8	3,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



PXX = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: I = 2021)
 M = Month (ex: 9 = September)

Date Code Key

Year	2010	...	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	X	...	I	J	K	L	M	N	O	P	R	S

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (2)	V _{CC}	-50	V
Input Voltage, (1) to (2) DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	V _{IN}	+10 to -10 +10 to -12 +10 to -30 +10 to -40 +5 to -5 +5 to -10 +5 to -12 +6 to -20	V
Input Voltage, (1) to (2) DDTB123TC DDTB143TC DDTB114TC DDTB114GC	V _{EBO(MAX)}	-5	V
Output Current All	I _C	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 5. Mounted on FR4 PC Board with minimum recommended pad layout.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.) R1, R2 Types

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	V _{I(off)}	-0.5 -0.5 -0.5 -0.5 -0.5 -0.3 -0.3 -0.3	—	—	V	V _{CC} = -5V, I _O = -100μA
	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	V _{I(on)}	—	—	-3.0 -3.0 -3.0 -3.0 -3.0 -2.0 -2.0 -2.0	V	V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -10mA V _O = -0.3V, I _O = -30mA V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA
Output Voltage		V _{O(on)}	—	—	-0.3	V	I _O /I _I = -50mA/-2.5mA
Input Current	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	I _I	—	—	-7.2 -3.8 -1.8 -0.88 -28 -7.2 -3.6 -2.4	mA	V _I = -5V
Output Current		I _{O(off)}	—	—	-0.5	μA	V _{CC} = -50V, V _I = 0V
DC Current Gain	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	G _I	33 39 47 56 47 56 56 56	—	—	—	V _O = -5V, I _O = -50mA
Gain-Bandwidth Product (Note 6)		f _T	—	200	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.) R1-Only, R2-Only Types

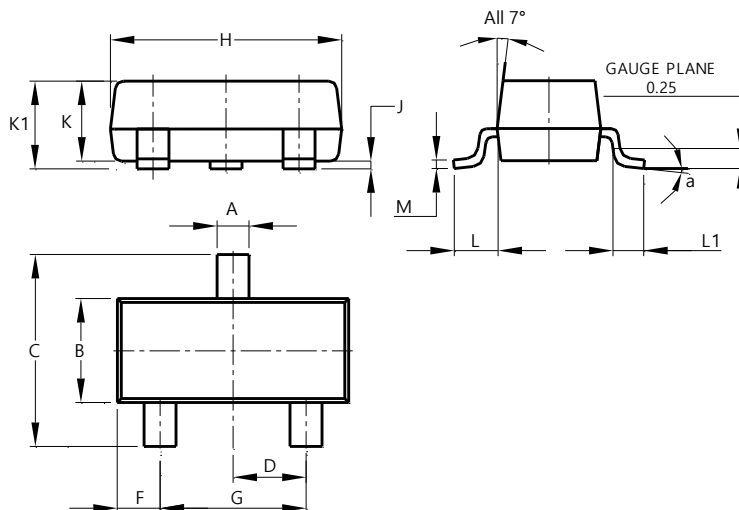
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV _{CBO}	-50	—	—	V	I _C = -50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	-40	—	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	BV _{EBO}	-5	—	—	V	I _E = -50μA I _E = -50μA I _E = -50μA I _E = -720μA
Collector Cutoff Current		I _{CBO}	—	—	-0.5	μA	V _{CB} = -50V
Emitter Cutoff Current	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	I _{EBO}	— — — -300	—	-0.5 -0.5 -0.5 -580	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—	—	-0.3	V	I _C = -50mA, I _B = -2.5mA
DC Current Transfer Ratio	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	h _{FE}	100 100 100 56	250 250 250 —	600 600 600 —	—	I _C = -5mA, V _{CE} = -5V
Gain-Bandwidth Product (Note 6)		f _T	—	200	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Note: 6. Transistor - For Reference Only.

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT23

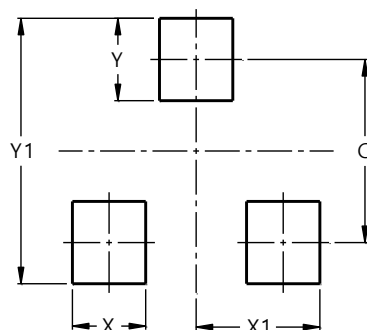


SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT23



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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